

SUPPORTING INFORMATION

for

**Conversion of methane to acetonitrile over GaN catalysts derived
from gallium nitrate hydrate co-pyrolyzing with melamine, melem, or
g-C₃N₄: the influence of nitrogen precursors**

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Table S1. The concentrations of Ga and N of used samples

Catalyst	Ga (wt%) ^a	N (wt%) ^b	N/Ga molar ratio
c-GaN	80.3	8.6	0.53
GaN-(melamine)-(1)	75.6	15.5	1.02
GaN-(melem)-(1)	72.5	15.4	1.06
GaN-(C ₃ N ₄)-(0.5)	73.9	15.1	1.02
GaN-(C ₃ N ₄)-(1)	73.7	15.4	1.04
GaN-(C ₃ N ₄)-(2)	75.9	15.2	1.00

^aEstimated by ICP-MS ; ^bEstimated by EA

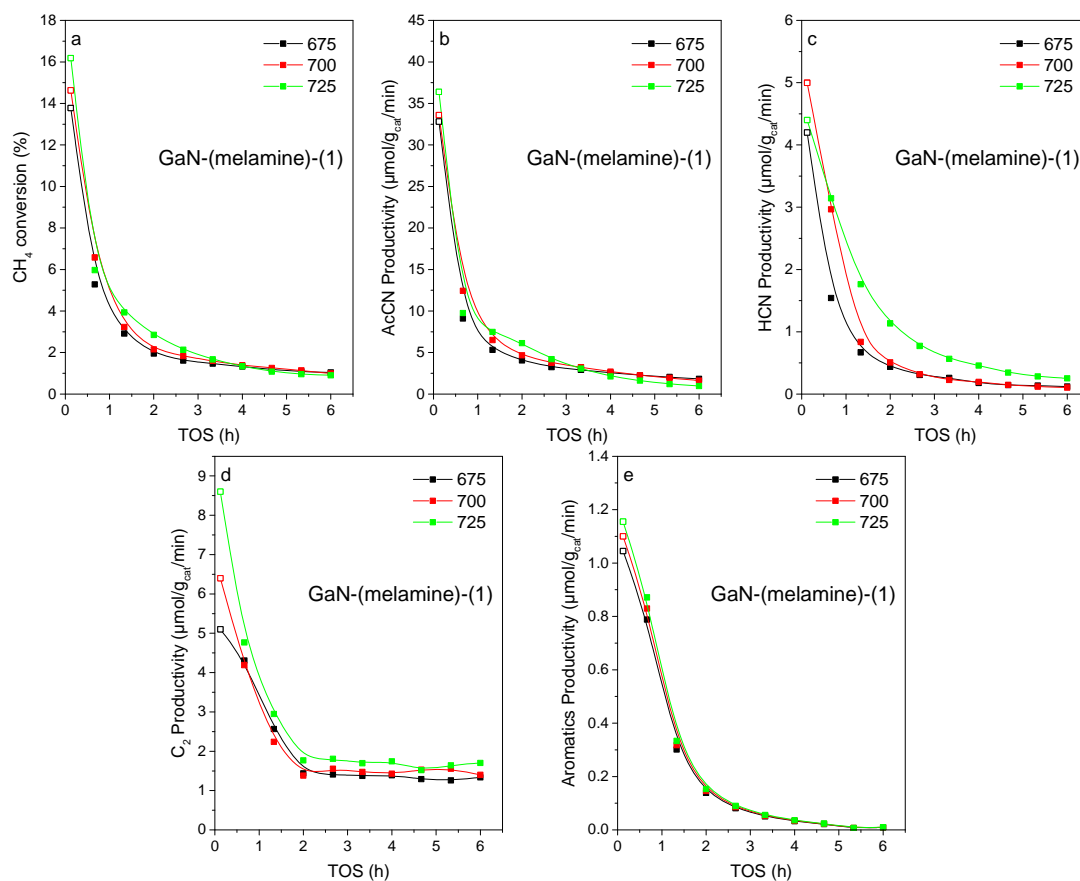


Figure S1. The TOS profiles of (a) CH₄ conversion and productivities of (b) AcCN, (c) HCN, (d) C₂, and (e) aromatics at 675, 700, and 725 °C with GHSV = 3000 mL_{CH₄}/g/h by testing GaN-(melamine)-(1). The open symbol means the initial activity calculated by using the MS signals; the closed symbol, calculated by the GC responses.

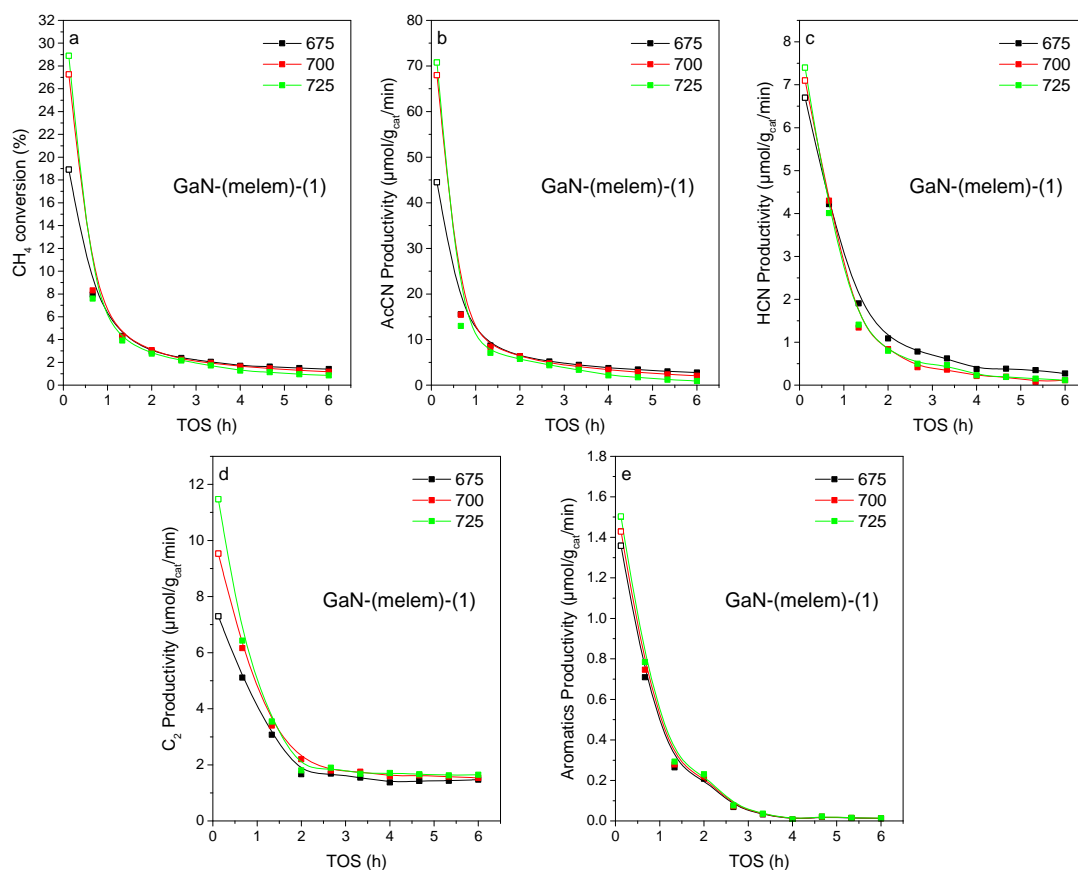


Figure S2. The TOS profiles of (a) CH₄ conversion and productivities of (b) AcCN, (c) HCN, (d) C₂, and (e) aromatics at 675, 700, and 725 °C with GHSV = 3000 mL_{CH₄}/g/h by testing GaN-(melem)-(1). The open symbol means the initial activity calculated by using the MS signals; the closed symbol, calculated by the GC responses.

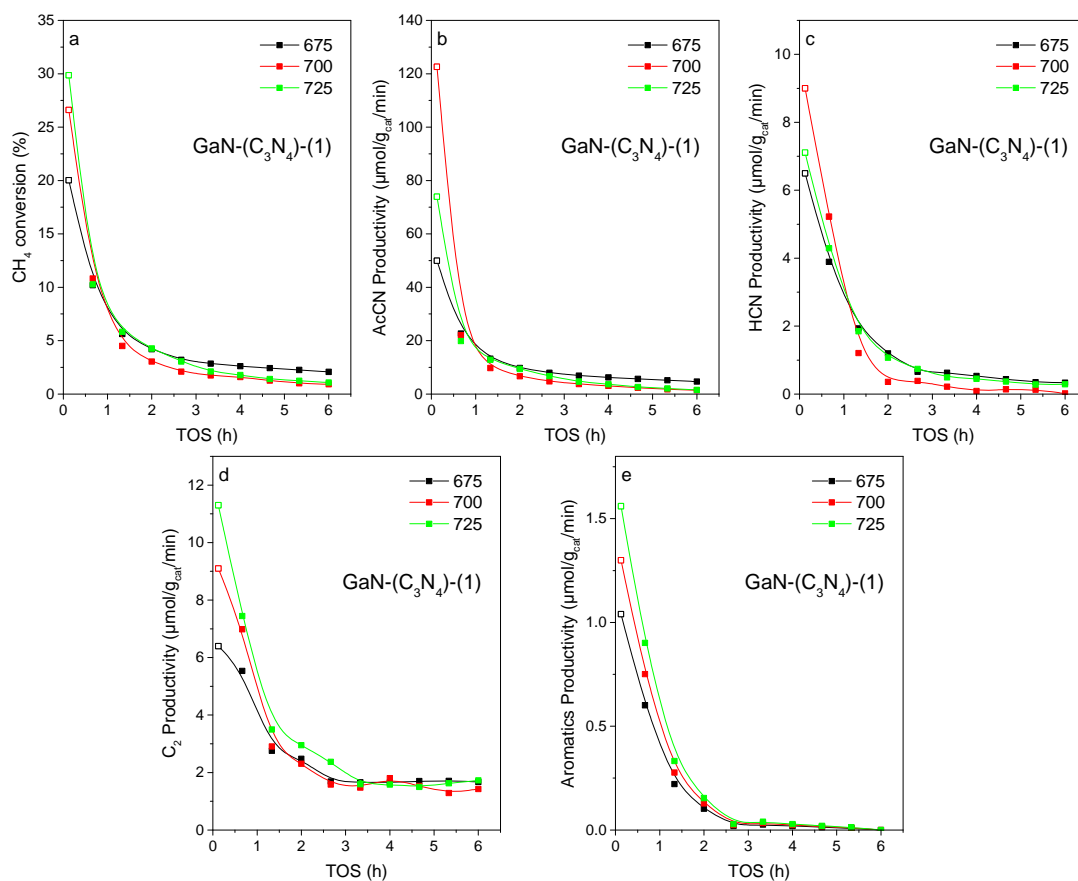


Figure S3. The TOS profiles of (a) CH₄ conversion and productivities of (b) AcCN, (c) HCN, (d) C₂, and (e) aromatics at 675, 700, and 725 °C with GHSV = 3000 mL_{CH₄}/g/h by testing GaN-(C₃N₄)-(1). The open symbol means the initial activity calculated by using the MS signals; the closed symbol, calculated by the GC responses.

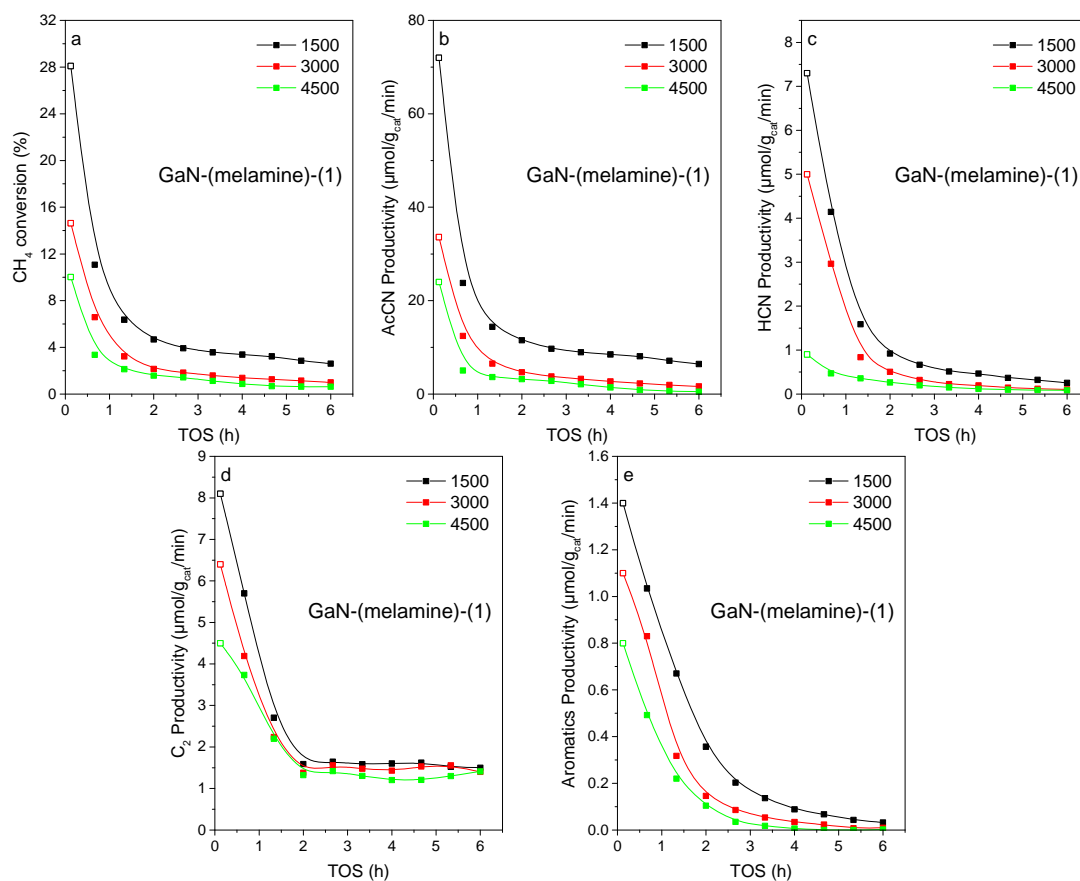


Figure S4. The TOS profiles of (a) CH₄ conversion and productivities of (b) AcCN, (c) HCN, (d) C₂, and (e) aromatics at 700 °C with GHSVs = 1500, 3000, and 4500 mL_{CH₄}/g/h by testing GaN-(melamine)-(1). The open symbol means the initial activity calculated by using the MS signals; the closed symbol, calculated by the GC responses.

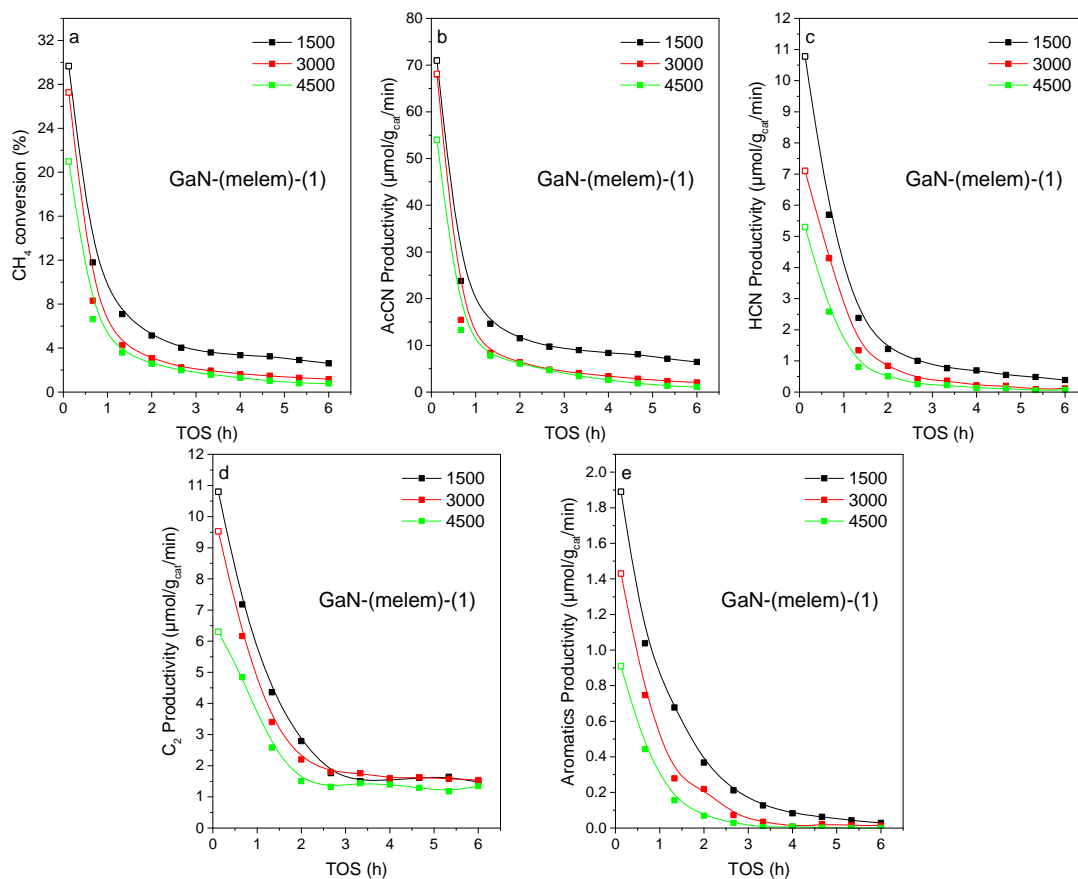


Figure S5. The TOS profiles of (a) CH₄ conversion and productivities of (b) AcCN, (c) HCN, (d) C₂, and (e) aromatics at 700 °C with GHSVs = 1500, 3000, and 4500 mL_{CH₄}/g/h by testing GaN-(melem)-(1). The open symbol means the initial activity calculated by using the MS signals; the closed symbol, calculated by the GC responses.

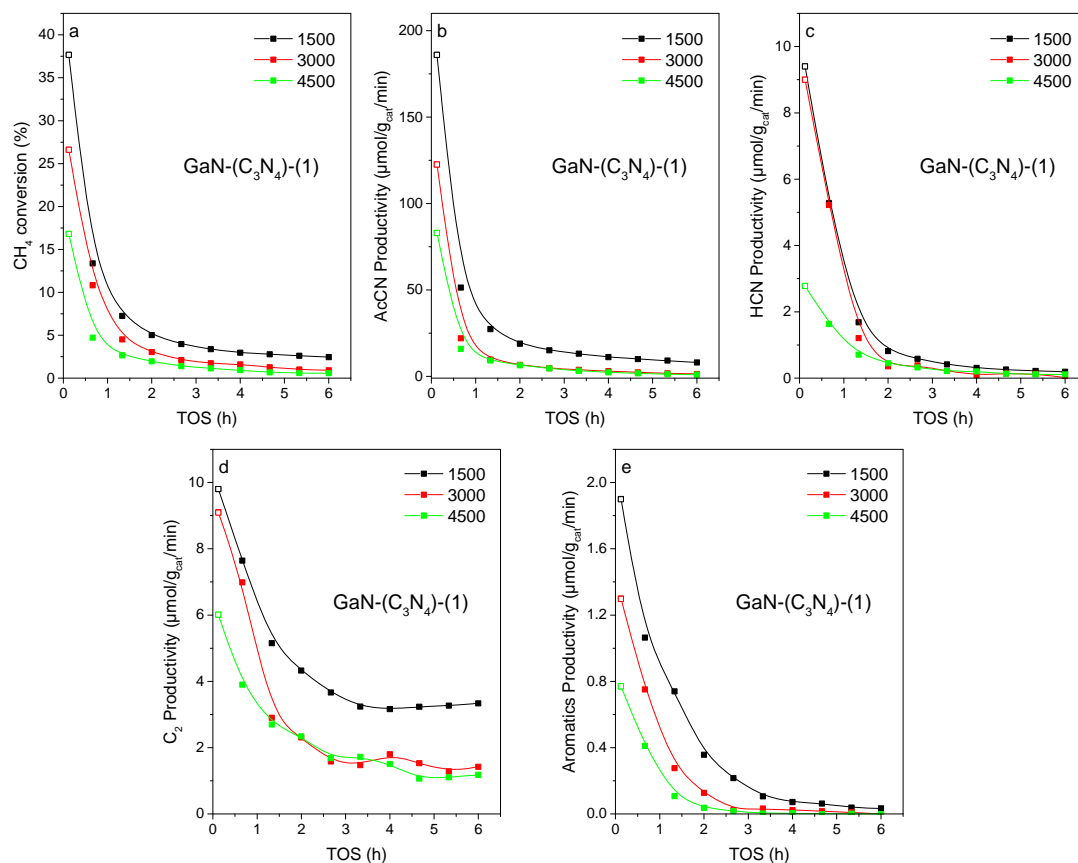


Figure S6. The TOS profiles of (a) CH₄ conversion and productivities of (b) AcCN, (c) HCN, (d) C₂, and (e) aromatics at 700 °C with GHSVs = 1500, 3000, and 4500 mL_{CH₄}/g/h by testing GaN-(C₃N₄)-(1). The open symbol means the initial activity calculated by using the MS signals; the closed symbol, calculated by the GC responses.

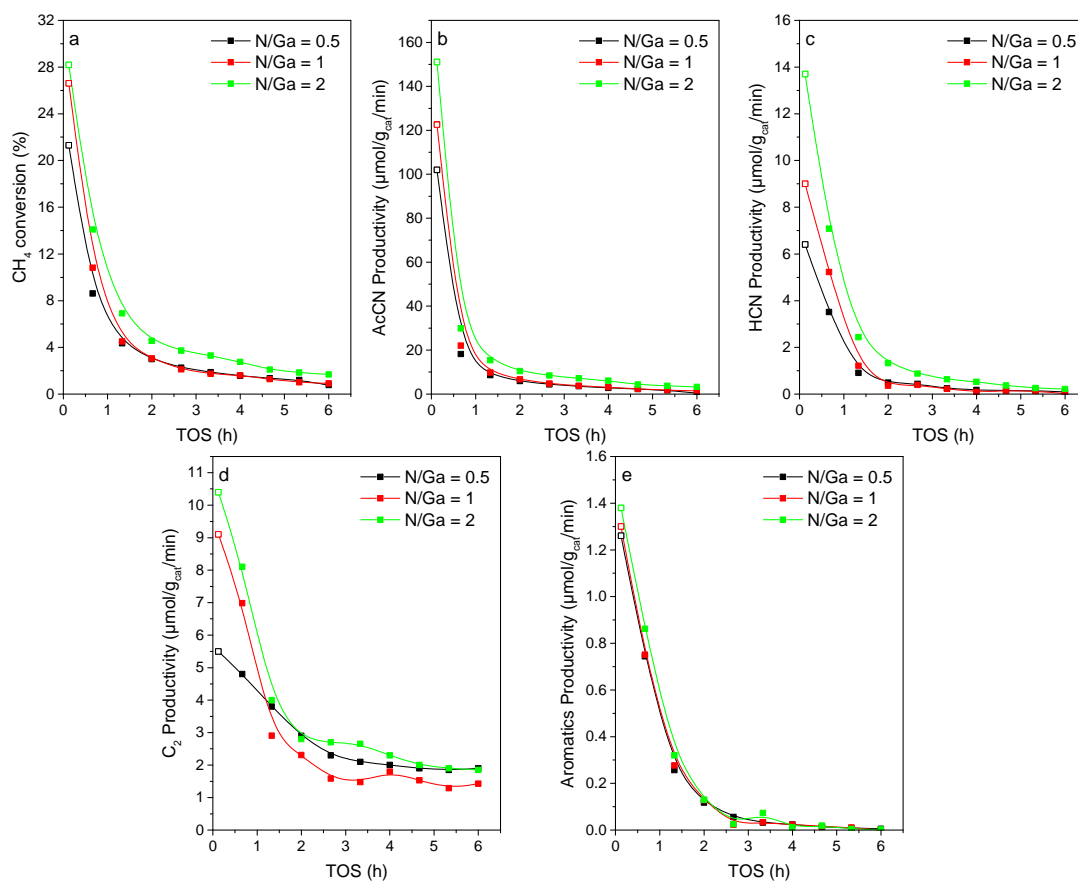


Figure S7. The TOS profiles of (a) CH_4 conversion and productivities of (b) AcCN, (c) HCN, (d) C_2 , and (e) aromatics at 700 °C with $\text{GHSV} = 3000 \text{ mL}_{\text{CH}_4}/\text{g}/\text{h}$ by testing GaN-(C_3N_4)-(0.5, 1, and 2) catalysts. The open symbol means the initial activity calculated by using the MS signals; the closed symbol, calculated by the GC responses.

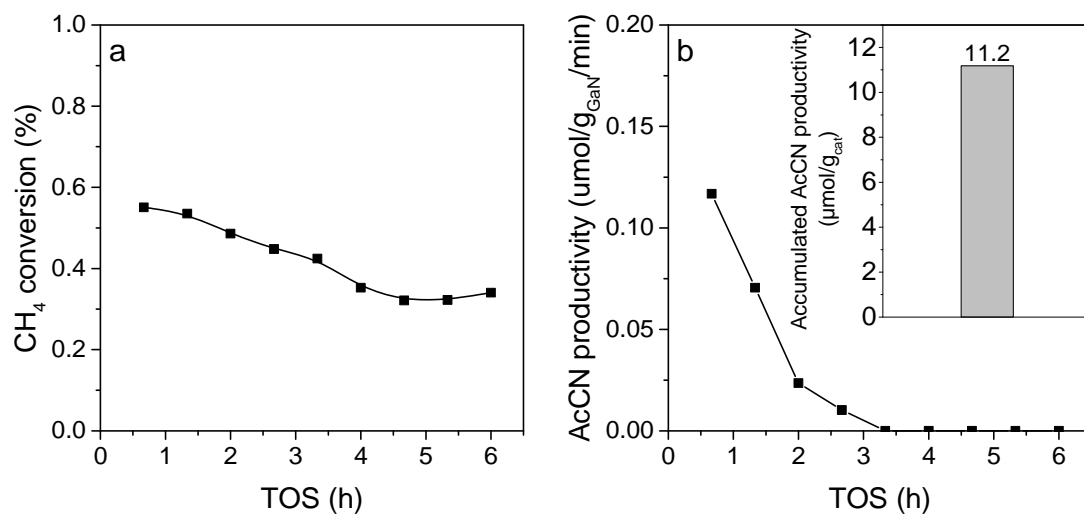


Figure S8. (a) The methane conversion and (b) AcCN productivity of c-GaN at 700 °C with GHSV = 3000 mL_{CH₄}/g/h.

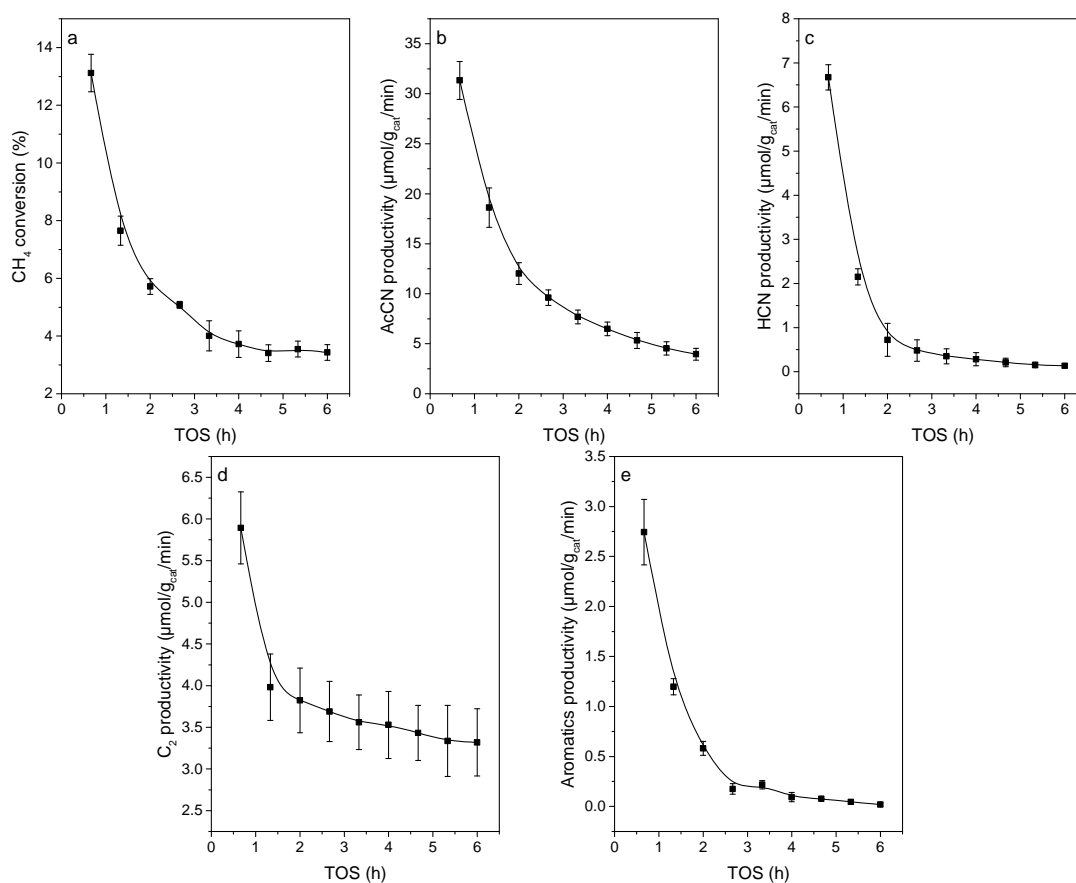


Figure S9. The TOS profiles of a reproducibility testing of (a) CH₄ conversion and productivities of (b) AcCN, (c) HCN, (d) C₂, and (e) aromatics at 700 °C with GHSV = 3000 mL_{CH₄}/g/h by testing GaN-(C₃N₄)-(2).

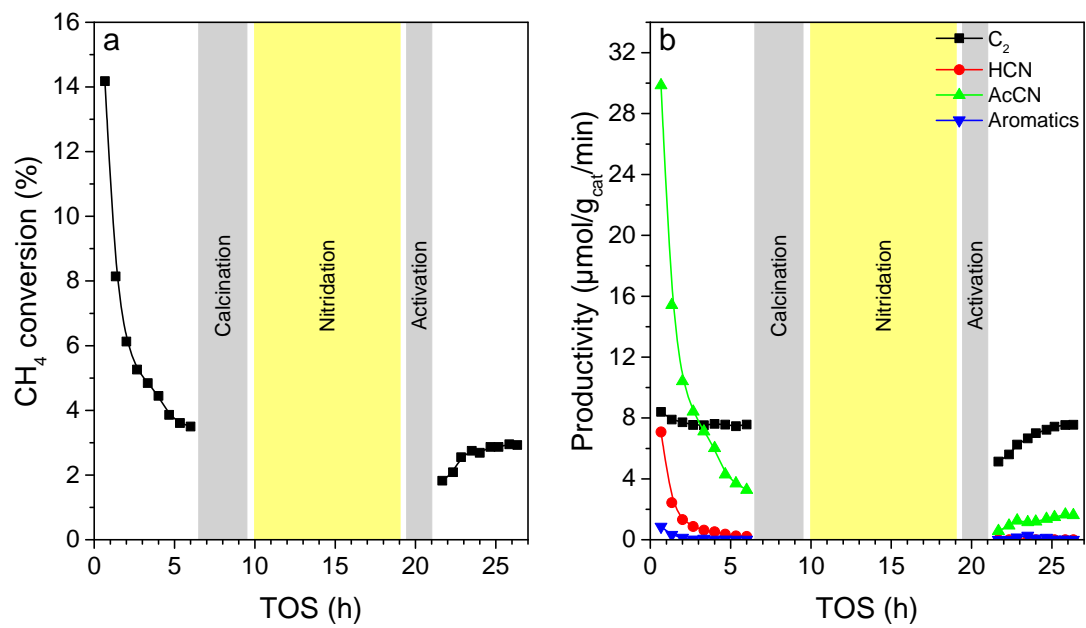


Figure S10. (a) Methane conversion and (b) productivities of AcCN, C₂, HCN, and aromatics of the regeneration test of GaN-(C₃N₄)-(2) using the calcination-nitridation method.

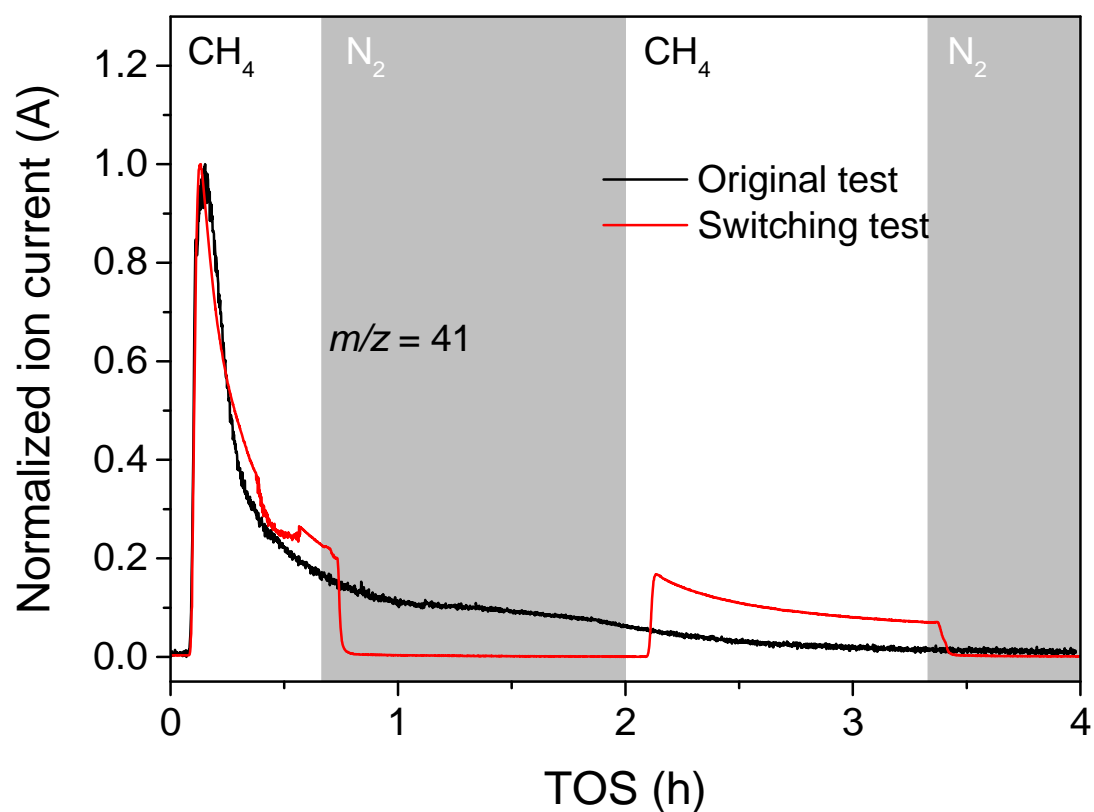


Figure S11. The AcCN MS signal ($m/z = 41$) of the alternating feeding test of $\text{CH}_4\text{-N}_2\text{-CH}_4$ using $\text{GaN-(C}_3\text{N}_4\text{)-(2)}$ as the catalyst at $700\text{ }^\circ\text{C}$ with a GHSV of $3000\text{ mL}_{\text{CH}_4}/\text{g}_{\text{cat}}/\text{h}$. Reaction conditions: $g_{\text{cat}} = 0.2\text{ g}$ and methane flow rate = $10\text{ mL}/\text{min}$. After collecting the data for 40 min, the flow was switched to a N_2 flow ($10\text{ mL}/\text{min}$). The N_2 flow was maintained for 80 min, and was then switched back to methane.

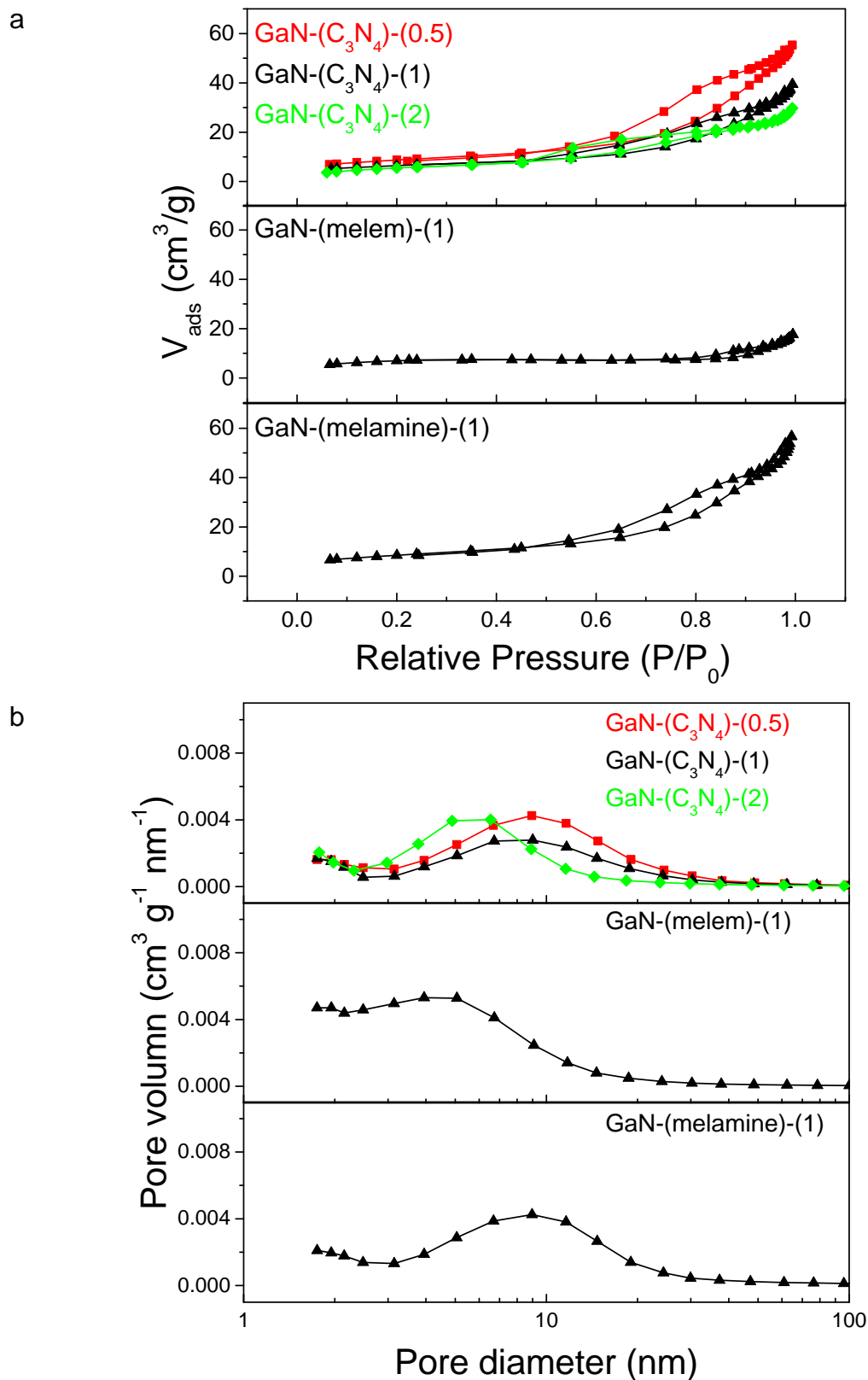


Figure S12. (a) The adsorption-desorption isotherms and (b) pore size distributions of tested catalysts.

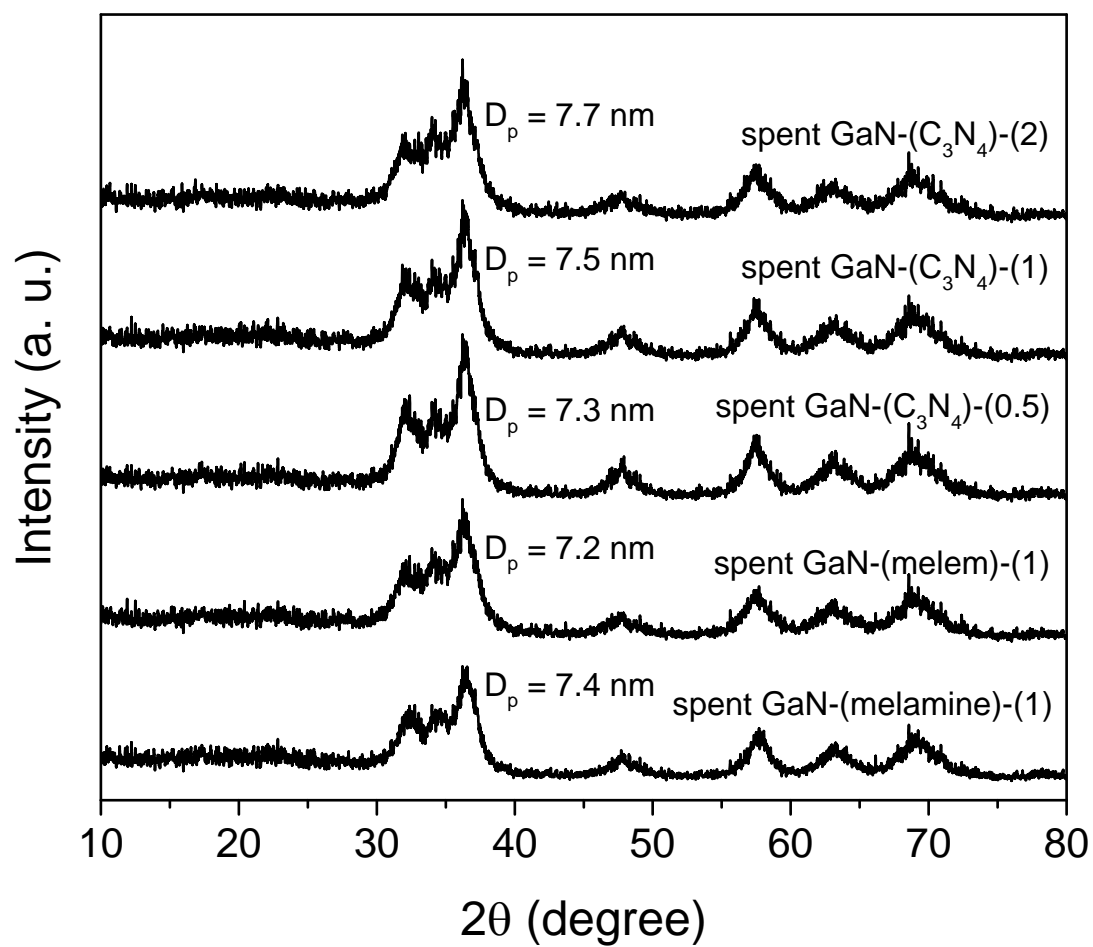


Figure S13. The XRD patterns of the post-reaction GaN catalysts.

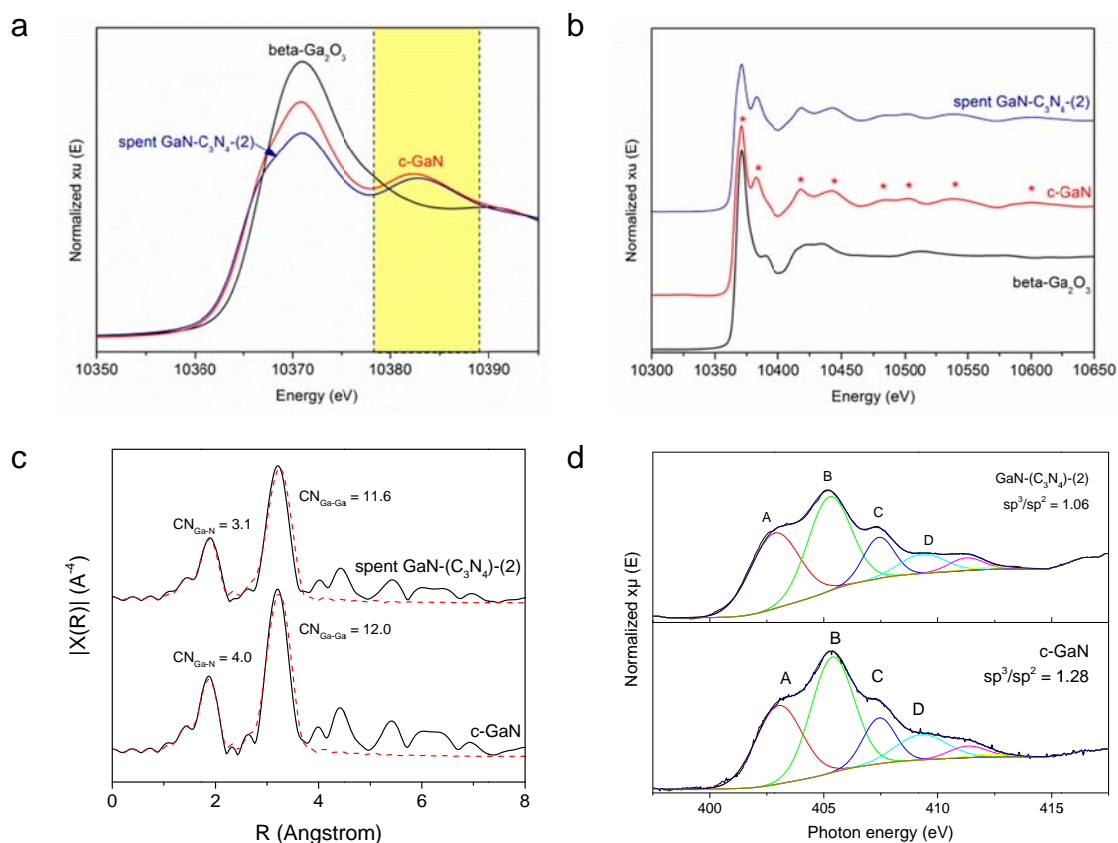


Figure S14. (a) Ga K -edge XANES and (b) the eight oscillation peaks (marked with asterisks) in the first 300 eV above the edge of spent GaN-(C₃N₄)-(2) and c-GaN. (c) Ga-N phase corrected RDFs of Ga K -edge for spent GaN-(C₃N₄)-(2) and c-GaN. The solid line represents the experimental data, and the dashed line represents the computer fit. (d) N K -edge XANES of spent GaN-(C₃N₄)-(2) and c-GaN. The fitted peaks of G₁ (red), G₂ (green), G₃ (blue), G₄ (cyan), G₅ (magenta), and G₆ (yellow) were included.

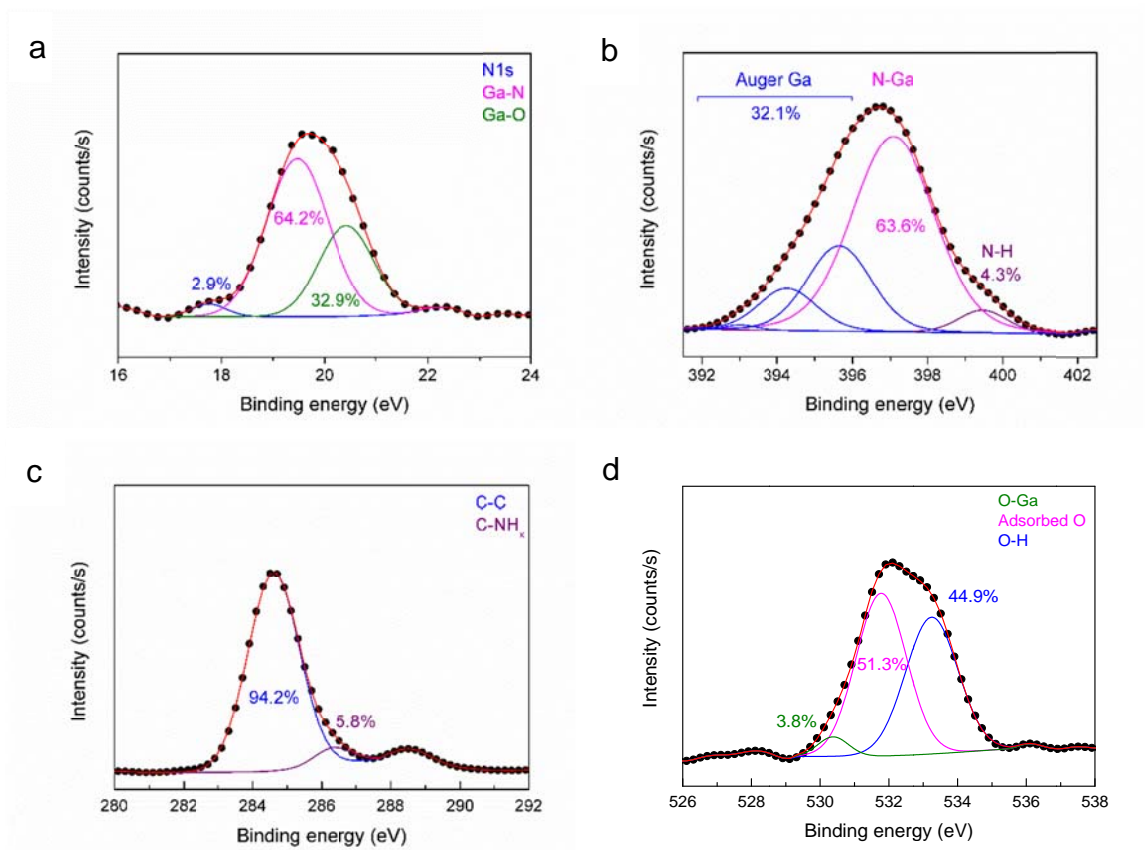


Figure S15. XPS spectra of (a) Ga 3d, (b) N 1s, (c) C 1s, and (d) O 1s photolines of c-GaN.

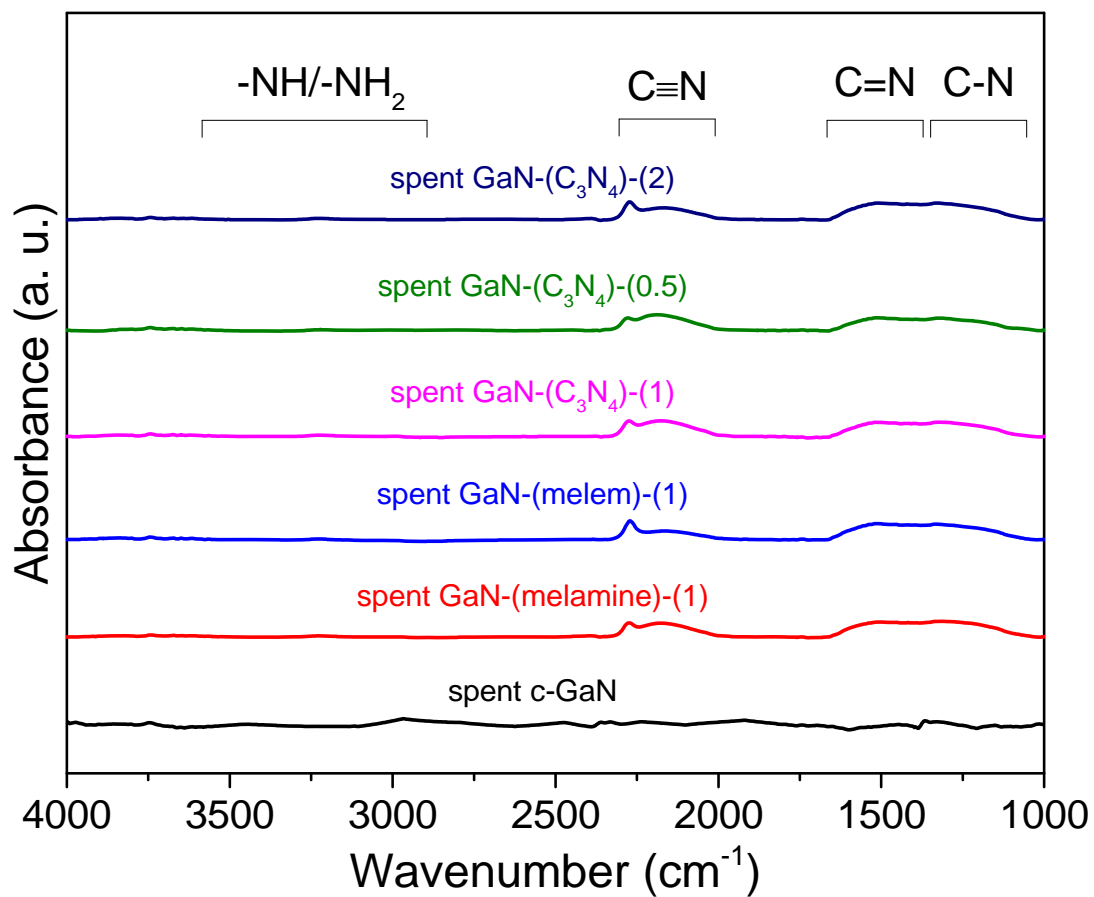


Figure S16. FTIR spectra of the post-reaction GaN catalysts.

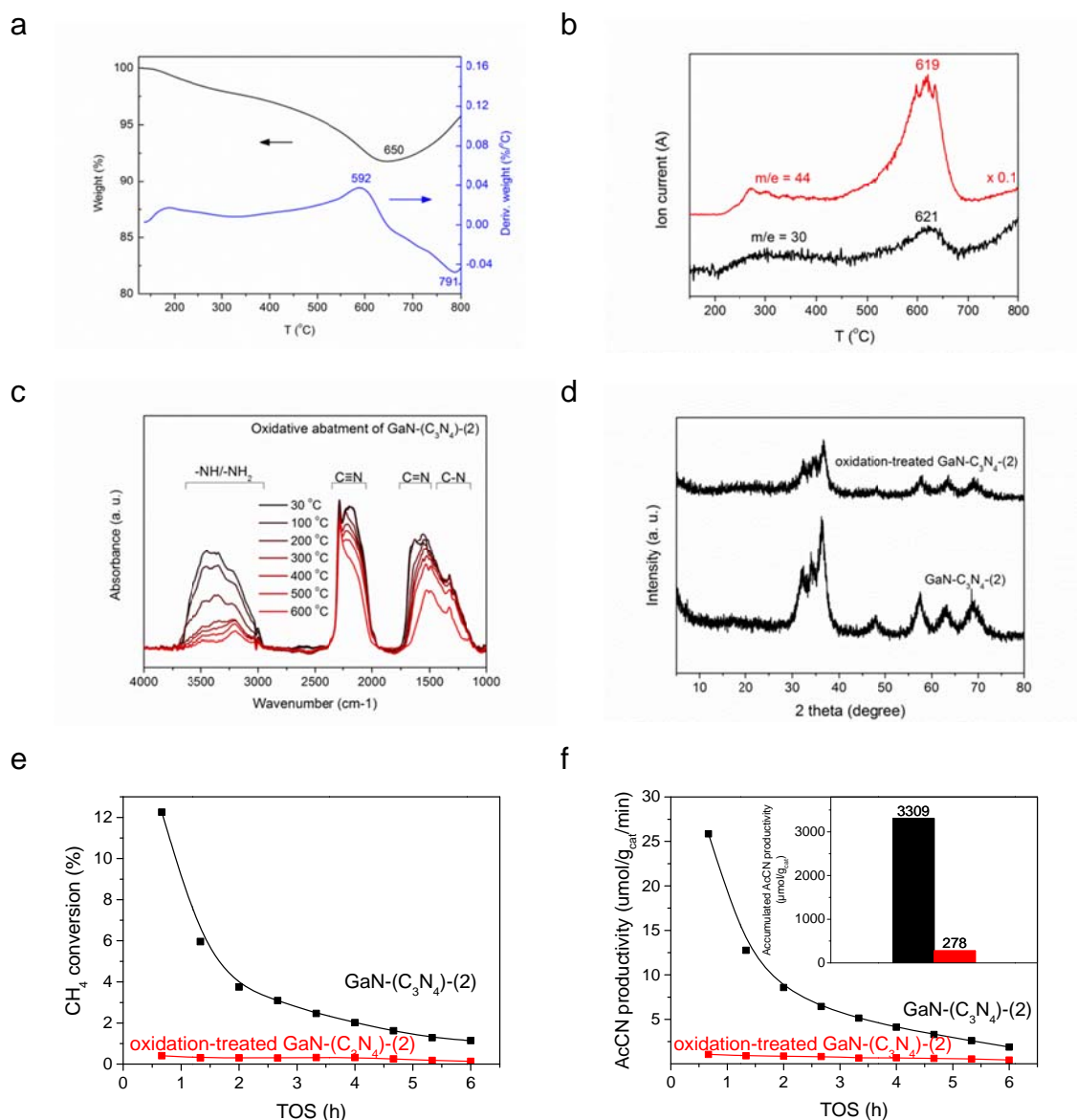


Figure S17. (a) TGA/DTA profiles, (b) the MS fragments ($m/e = 30$ and 44) of $\text{GaN}-(\text{C}_3\text{N}_4)-(2)$ in an air stream (100 mL/min). (c) The temperature-resolved in-situ IR spectra of $\text{GaN}-(\text{C}_3\text{N}_4)-(2)$ from 30 to $600 \text{ }^\circ\text{C}$ in a $10\% \text{ O}_2/\text{N}_2$ stream (20 mL/min). (d) The XRD patterns of $\text{GaN}-(\text{C}_3\text{N}_4)-(2)$ after subjecting to the oxidative abatement and its fresh counterpart. (e) Methane conversion and (f) AcCN productivity of $\text{GaN}-(\text{C}_3\text{N}_4)-(2)$ after subjecting to the oxidative abatement at $700 \text{ }^\circ\text{C}$.

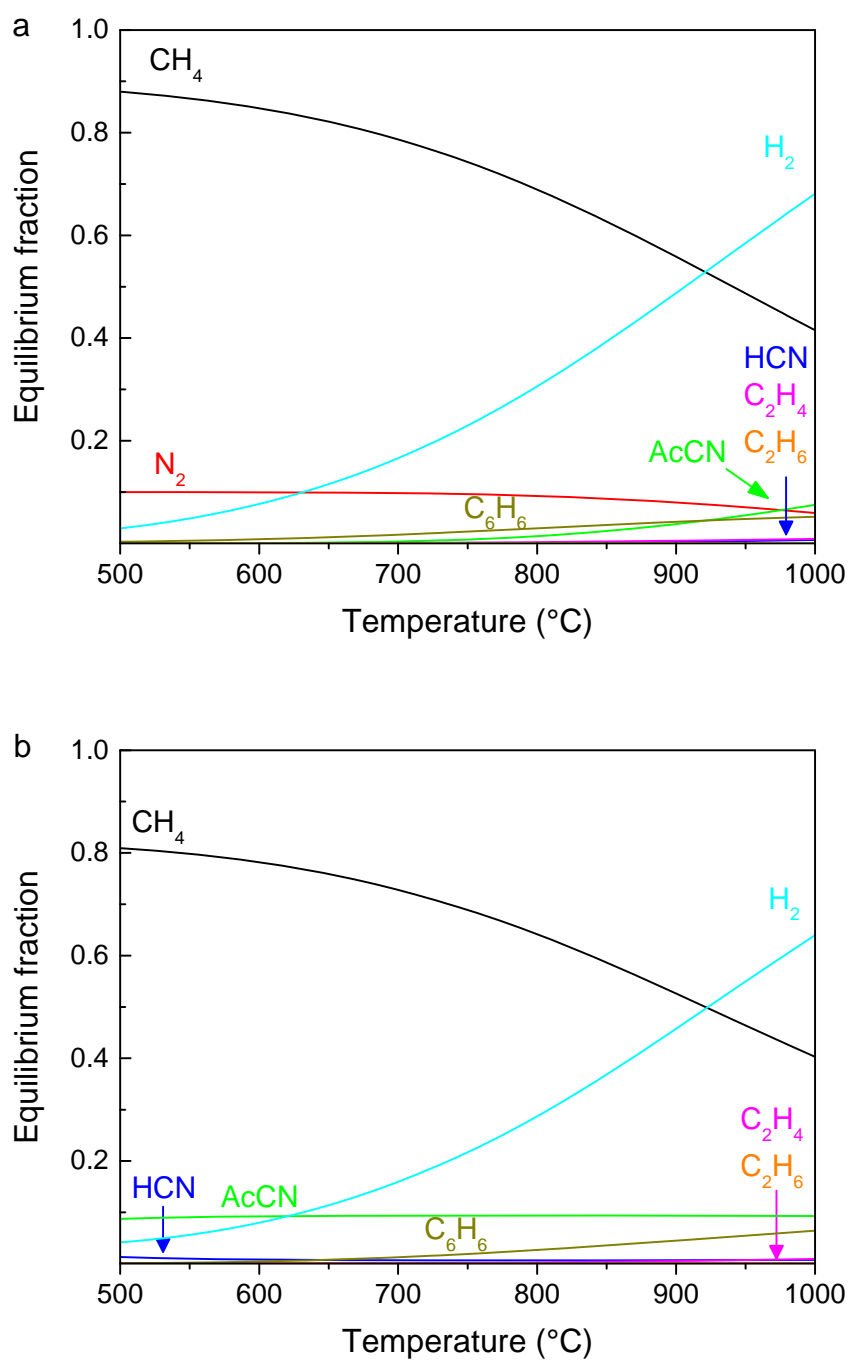


Figure S18. Calculated equilibrium compositions of AcCN, HCN, H_2 , C_2H_4 , C_2H_6 , and C_6H_6 using (a) CH_4 and N_2 and (b) CH_4 and CN as the feeds (CH_4/N_2 or $\text{CH}_4/\text{CN} = 9/1$) in 500 to 1000 °C under ambient pressure.

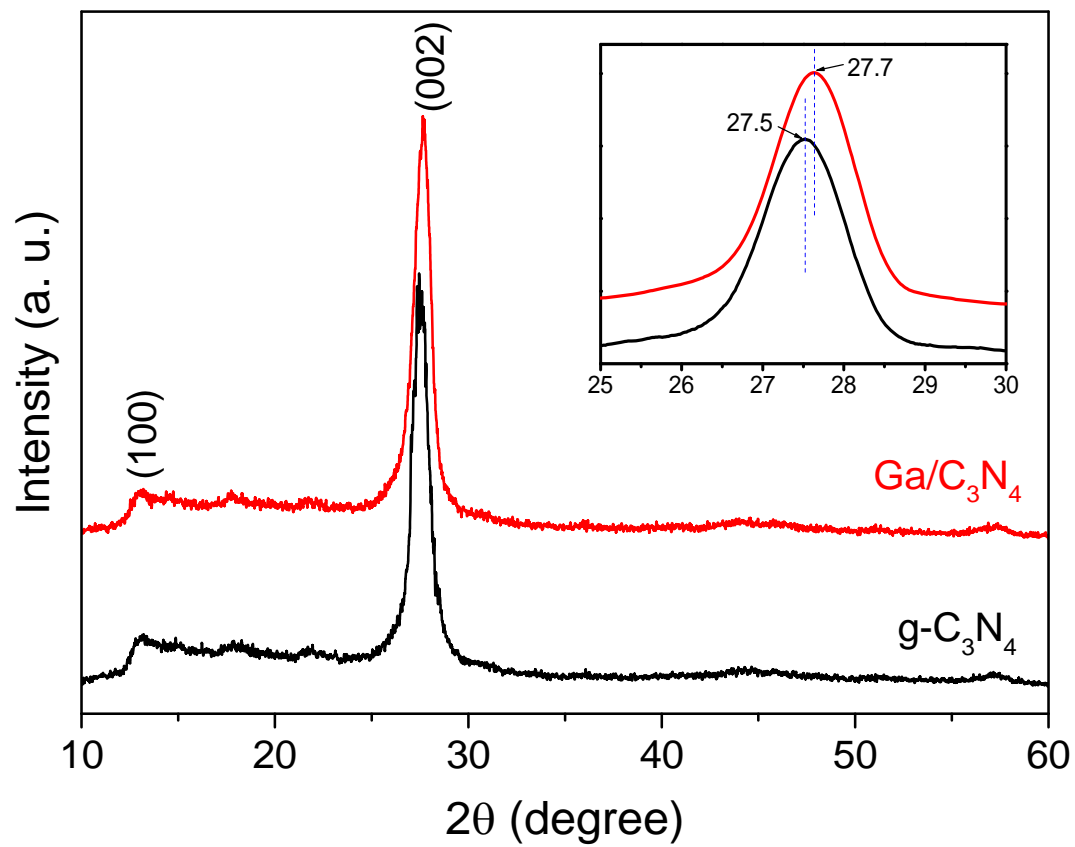


Figure S19. XRD patterns of $\text{g-C}_3\text{N}_4$ and 550°C pyrolyzed precursor ($\text{Ga/C}_3\text{N}_4$).

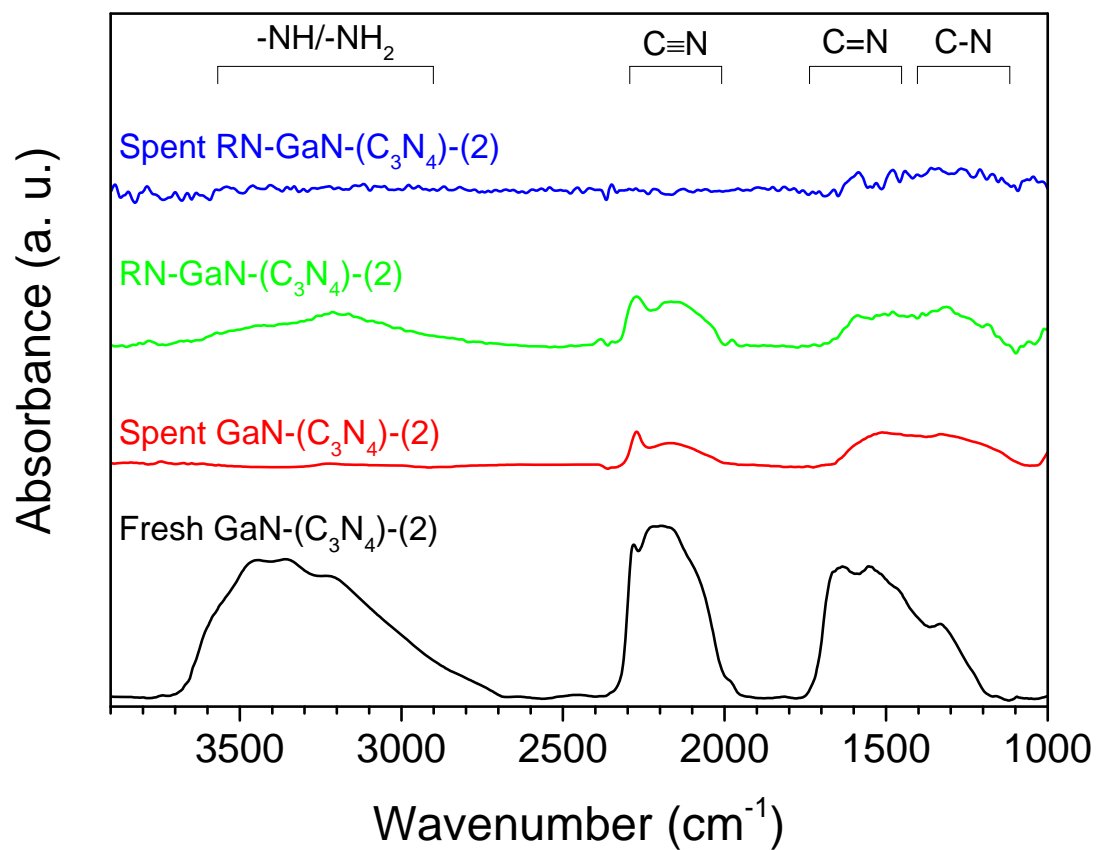


Figure S20. FTIR spectra of fresh GaN-(C₃N₄)-(2) (black), spent GaN-(C₃N₄)-(2) (red), regenerated GaN-(C₃N₄)-(2) (RN-GaN-(C₃N₄)-(2), before the 2nd on-stream test, green), and spent RN-GaN-(C₃N₄)-(2) (after the 2nd on-stream test, blue).

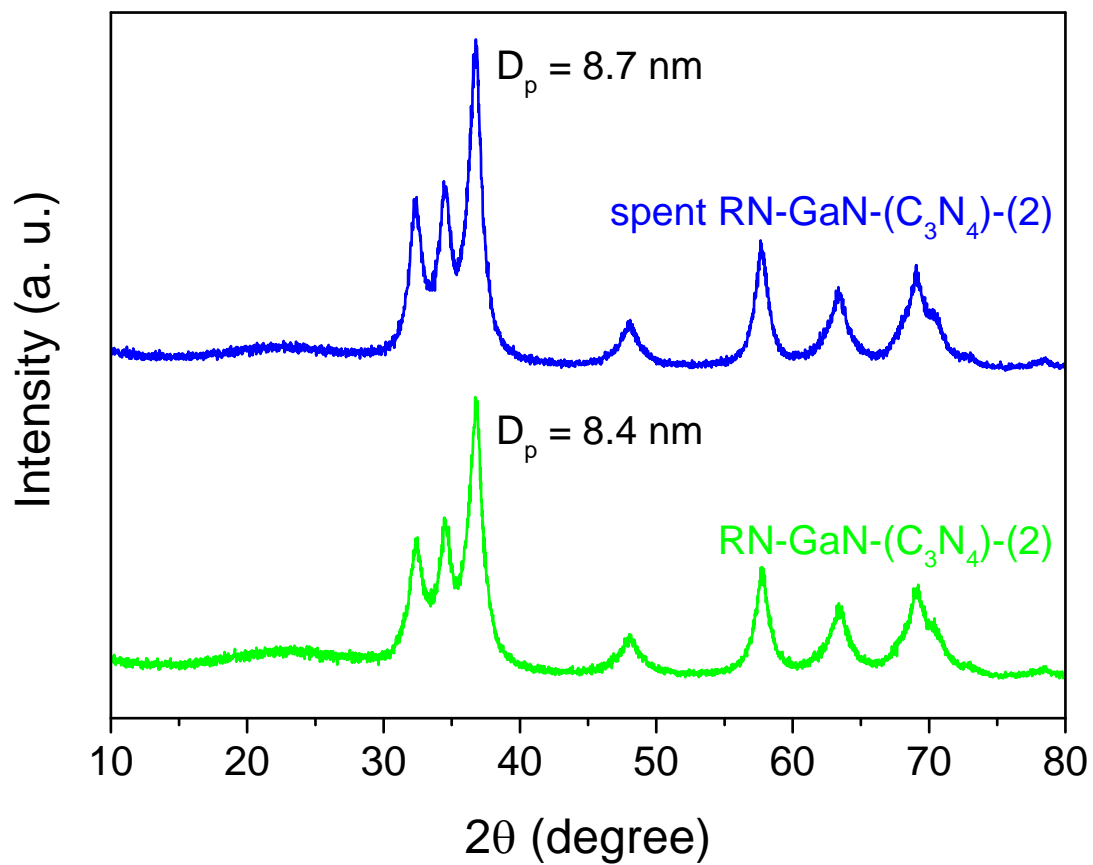


Figure S21. The XRD patterns of regenerated GaN-(C₃N₄)-(2) (RN-GaN-(C₃N₄)-(2), before the 2nd on-stream test, green) and spent RN-GaN-(C₃N₄)-(2) (after the 2nd on-stream test, blue).